Effect of Ni Doping on the MoS$_2$ Structure and Its Hydrogen Evolution Activity in Acid and Alkaline Electrolytes

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Received: 28 October 2019; Accepted: 29 November 2019; Published: 3 December 2019

Abstract: We have investigated three-dimensional (3D) MoS$_2$ nanoarchitectures doped with different amount of Ni to boost the hydrogen evolution reaction (HER) in alkaline environment, where this reaction is normally hindered. As a comparison, the activity in acidic media was also investigated to determine and compare the role of the Ni sites in both media. The doping of MoS$_2$, especially at high loadings, can modify its structural and/or electronic properties, which can also affect the HER activity. The structural and electronic properties of the Ni doped 3D-MoS$_2$ nanoarchitecture were studied by X-ray diffraction (XRD), Raman spectroscopy, scanning and transmission electronic microscopy (SEM; TEM), and X-ray photoemission Spectroscopy (XPS). XPS also allowed us to determine the Ni-based species formed as a function of the dopant loading. The HER activity of the materials was investigated by linear sweep voltammetry (LSV) in 0.5 M H$_2$SO$_4$ and 1.0 M KOH. By combining the physicochemical and electrochemical results, we concluded that the Ni sites have a different role in the HER mechanism and kinetics in acidic and alkaline media. Thus, NiS$_x$ species are essential to promote HER in alkaline medium, whereas the Ni-Mo-S ones enhance the HER in acid medium.

Keywords: HER; TMDC; electrocatalysis; doping; electron spectroscopy

1. Introduction

Nowadays, molecular hydrogen is considered the most promising energy vector for developing a sustainable energy infrastructure based on the efficient interconversion of chemical energy into electricity and vice versa, also known as hydrogen economy [1]. Therefore, the development of new technologies for clean and cost-effective large-scale production of hydrogen is of utmost importance. Electrolyzers based on the water splitting (WS) are, so far, the most promising devices to obtain clean hydrogen through the hydrogen evolution reaction (HER) at the cathode side of an electrochemical cell [2]. This, however, requires the development and optimization of electrocatalysts, based on cost-effective noncritical raw materials (i.e., noble metal-free), that may guarantee efficiency and
durability under operating conditions. As WS also entails the oxygen evolution reaction at the anode side, which requires the use of alkaline conditions when catalyzed by non-noble metal catalysts, many efforts are currently focusing on the identification of new electrocatalysts that can catalyze the HER in alkaline media.

The influence of the pH on the cathodic half-reaction can be easily portrayed starting from the two accredited mechanisms for HER (i.e., Volmer–Heyrovsky and Volmer–Tafel) that result from the combination of two of the following reactions steps [3–5].

Volmer step (Electrochemical Hydrogen Adsorption):
\[ \text{Acid: } H_3O^+ + e^- \rightarrow H_{ads} + H_2O \]
\[ \text{Base: } H_2O + e^- \rightarrow H_{ads} + OH^- \]

Heyrovsky step (Electrochemical Desorption):
\[ \text{Acid: } H_{ads} + H_3O^+ + e^- \rightarrow H_2 + H_2O \]
\[ \text{Base: } H_{ads} + H_2O + e^- \rightarrow H_2 + OH^- \]

Tafel Step (Chemical Desorption):
\[ 2H_{ads} \rightarrow H_2 \]

Therefore, the HER electrocatalyst performance is dramatically influenced by pH, as different species have to be adsorbed and reduced in steps where H_3O^+/OH^- are involved. For instance, Durst et al. demonstrated that, in the case of noble metals (Pt, Ir and Ru), the catalytic activity can decrease by two orders of magnitude at high pH [3]. This quite general phenomenon suggests that the energy needed to break the covalent H–OH bond, must be higher than that required by the dative ‘H–OH’ bond [4]. Moreover, hydroxyl anions could poison the metal sites, so hindering the catalytic activity by strongly adsorbing even on precious metal-based catalysts. Recently, a quite complex debate in the literature has started [4], where the traditional theoretical approach, to predict HER based on the hydrogen adsorption energy as the sole reaction descriptor [3,6], has been challenged to take into account the much more complex phenomenology of the alkaline environment [7].

As an alternative to the Platinum Group Metals (PGMs) based catalysts, which are nowadays in the list of the Critical Raw Materials (CRMs) [8,9], many types of earth-abundant transition metal-based catalysts are intensively investigated [10,11]: metals; alloys; carbides; nitrides [12]; borides [13,14]; and, above all, transition metals dichalcogenides (TMDCs) [15]. TMDCs are 2D-layered materials that have been extensively studied as HER electrocatalysts. Although many papers report on experiments in acidic media, only few studies deal with the electroactivity in alkaline conditions [4,15–17]. As demonstrated by Wiensch et al., MoS_2 has a variety of possible sites for the HER at different pH [17]. Mo-terminated edge sites are active at low pH because of the thermoneutral adsorption of hydrogen on the Mo site. On the contrary, in a hydroxyl rich environment, the formation of Mo-H species is inhibited and the S-rich terraces become the preferential sites for the HER [18]. As proven by calculations, on the Mo-edge in alkaline conditions, the dissociation of water is the rate determining step, because the formation of strong Mo–OH bond slows down the OH^- desorption hindering the Volmer step [19,20].

However, TMDCs have some critical issues, such as a limited electrical conductivity and restacking phenomena. Several strategies are currently tested to improve the HER activity of MoS_2: doping with transition metals [21–25], anion substitution [26–28], preparation of composites [29–31], or materials with special morphologies [32,33]. Tsai et al. screened the effect of 19 transition metals dopants on MoS_2 by DFT calculations [34]. Moreover, several experimental tests proved that the substitution of Mo cations with other metal can boost the HER performance of MoS_2 through electronic and/or structural effects [18,20,35].

In this paper, we combine the transition metal doping approach with the 3D material design. Actually, moving from simple 2D sheets [16,36–41] to 3D-structured systems [42–48] a higher number of exposed catalytic sites can be produced. We prepared 3D-structured MoS_2 samples (hereafter 3D-MoS_2) through a simple bottom-up strategy that allowed introducing the dopant by a simple one-pot procedure. We studied the effect of Ni doping on the 3D-MoS_2 nanoarchitecture and we investigated the HER activity, in both acidic and alkaline media. Gathering all the data, we observed a strong influence of the doping on the MoS_2 crystallization and structure, with strong effects on the final performances and reaction kinetics.
2. Materials and Methods

2.1. General

Ammonium molybdate (NH₄)₆Mo₇O₂₄·4H₂O (>99.3%), aqueous (NH₄)₂S solution (20 wt %), sulfuric acid (95%–97%), potassium hydroxide (85%), N,N-dimethylformamide (99%), and Nafion solution (5 wt % solids in alcohol and water) were purchased from Sigma-Aldrich (Milan, Italy) and used without any further purification. NiCl₂·6H₂O (99.95%) was purchased from Alfa Aesar (Kandel, Germany) and used as received. Pt/C (20 wt %. loading) was acquired from Johnson Matthey (London, United Kingdom).

2.2. Ammonium Tetrathiomolybdate (ATM) Synthesis

Details of the ATM preparation, the starting material for the synthesis of the 3D-MoS₂, are reported in the Supplementary Information material (SI).

2.3. Synthesis of 3D-MoS₂ and Ni-Doped 3D-MoS₂

To study the effect of the ATM concentration on the 3D-MoS₂ structure, samples with three different ATM concentrations were prepared. In particular, ATM (300 mg; 1.15 mmol) was dissolved in 60, 30, or 12 mL of water (milliQ 18.2 MΩ, degassed with N₂ for 1 h), obtaining 5, 10, and 25 mg mL⁻¹ concentration, respectively, and kept under stirring for 2 h. The solution was frozen by dipping the flask into liquid nitrogen and freeze-dried in vacuum. The powder was then treated at 450 °C for 4 h (10 °C min⁻¹ ramp) in 95:5 Ar:H₂ atmosphere (100 sccm total flow) in a tubular furnace. After cooling down to RT, the so-obtained gray powder was collected and stored under nitrogen to prevent surface oxidation. The samples (labeled as 3D-MoS₂-X, with X = 5, 10 and 25 mg mL⁻¹) were tested, the 3D-MoS₂-10 sample was the most active toward the HER (see ESI). Therefore, this is the concentration used for the Ni doping study.

For the synthesis of the Ni-doped 3D-MoS₂ samples, NiCl₂·6H₂O was added to the ATM solution, and the same one-pot synthesis was followed. The amount of precursor was designed to obtain a Ni doping of 2, 5, 10, or 15 at.% vs. Mo (5.5, 13.7, 27.4, and 41.1 mg of NiCl₂·6H₂O, respectively).

2.4. Physico-Chemical Characterization

Scanning electron microscopy (SEM) micrographs were acquired using a field-emission source equipped with a GEMINI column (Zeiss Supra VP35, Carl Zeiss S.p.A., Milan, Italy) with an acceleration voltage of 5 kV using secondary electron detection.

Annular dark-field scanning transmission electron microscopy (ADF-STEM) and Energy-dispersive X-ray spectroscopy (EDS) analyses were performed using a JEOL JEM-1400Plus transmission electron microscope (Jeol Italia s.p.a., Milan, Italy) with LaB₆ thermionic source operated at 120 kV. The EDS maps were acquired using a JEOL Dry SD30GV silicon-drift detector (SDD), with 30 mm² effective area.

X-ray diffraction (XRD) characterization was performed with a Philips PW 1729 diffractometer (Koninklijke Philips N.V., Amsterdam, Netherlands), configured with a glancing angle geometry, operating with Cu Kα radiation (λ = 0.15406 nm) generated at 30 kV and 40 mA. The mean crystallite size was calculated from the MoS₂ (002) peak using the Scherrer equation: \( L_c = \frac{k \lambda}{\beta \cos \theta} \), where \( k \) is the shape factor (k = 0.9), \( \lambda \) is the X-ray wavelength, \( \beta \) is the line broadening at half the maximum intensity of the peak, and \( \theta \) is the Bragg angle. The XRD spectra of 2H-MoS₂ and 3R-MoS₂ were calculated with Vesta software (3.4.4).

Raman spectra were obtained with a ThermoFisher DXR Raman microscope (Thermo Fisher Scientific, Milan, Italy). The spectra were recorded using a laser with an excitation wavelength of 532 nm (0.1 mW), focused on the sample with a 50× objective (Olympus Italia s.r.l., Milan, Italy).

X-ray photoemission spectroscopy (XPS) data were acquired by a custom-designed UHV system equipped with an EA 125 Omicron electron analyzer with five channeltrons (Scicenta Omicron GmbH, Taunusstein, Germany), working at a base pressure of 10⁻¹⁰ mbar. Core level photoemission spectra
were taken in normal emission using the Mg Kα emission line \((\hbar \nu = 1253.6\ \text{eV})\) of a non-monochromated dual-anode DAR400 X-ray source. High-resolution spectra were acquired using 0.5 s dwell time, 0.1 eV energy steps, and 20 eV pass energy. In the case of the Ni 2p\textsubscript{3/2} region, the parameters were set to 0.25 s dwell time, 0.2 eV energy step, and 50 eV pass energy to obtain a better signal-to-noise ratio. In the same conditions, a set of measurements (not shown) of Mo 3d and S 2p core levels was acquired as well to calculate the surface composition. The multipoint analysis of the S 2p, Mo 3d and Ni 2p\textsubscript{3/2} photoemission lines was performed by means of Gaussian–Lorentzian functions and subtracting a Shirley background using the KolXPD software (1.8.0, Kolibrik.net, s.r.o., Žďár nad Sázavou, Czech Republic) [49].

2.5. Electrochemical Characterization

The electrochemical studies were performed in a conventional three-electrode electrochemical cell, using an Ag/AgCl (3 M KCl) electrode (calibrated as +0.218 V vs. the reversible hydrogen electrode, RHE) and a Pt wire as reference and counter electrode, respectively. For the long duration chrono-potentiometric measurements, a glassy carbon (GC) rod was used as counterelectrode. The working electrode was prepared by depositing 2.5 µL of catalyst ink on a GC electrode (2.8 mm diameter), corresponding to an active material loading of 142 µg cm\textsuperscript{−2}. The catalyst ink consisted of 2 mg of active material and 2 mg of Vulcan XC-72 carbon, ground in a mortar, and subsequently suspended in 0.5 mL of N\textsubscript{2},N\textsubscript{2}-dimethylformamide and 5 µL of Nafion solution. Carbon was added to the catalyst layer in order to increase its electrical conductivity and to obtain a homogeneous catalyst layer on the glassy carbon electrode. A Pt/C ink was prepared by dispersing 2 mg of commercial Pt/C (JM, Reading, United Kingdom, 20 wt %) and 5 µL of Nafion solution in 0.5 mL of water:ethanol mixture (1:1, \(v/v\)). 2.5 µL of Pt catalyst ink were deposited on a GC electrode (2.8 mm diameter). The measurements were carried out in N\textsubscript{2}-saturated 0.5M H\textsubscript{2}SO\textsubscript{4} or 1.0M KOH at room temperature. Polarization curves were recorded from +0.2 V to −0.5 V vs. RHE using a scan rate of 0.005 V s\textsuperscript{−1}. Currents presented in the text are normalized by the geometrical area and \(iR\)-corrected by using the resistance determined by electrochemical impedance spectroscopy (EIS) measurements. EIS was performed at \(\eta = 0.28\ \text{V} (100 \text{kHz to 0.1 Hz})\) and fitted using a R(Q) as equivalent circuit.

3. Results

3.1. Synthesis and Physicochemical Characterization

First, we optimized the synthesis of 3D-MoS\textsubscript{2} scaffold to maximize the HER performance of the pure material (see Figure S1 and discussion in Supplementary Materials). Then, we studied the effect of Ni loading (2%, 5%, 10%, and 15% at. Vs. Mo) on the optimized scaffold, starting from the structural changes induced by the doping insertion. In Figure 1A, we report a SEM image of the resulting scaffold where the typical lamellar structure of MoS\textsubscript{2} is evident. The same lamellar structure is maintained after all the different Ni-doping, as reported in Supplementary Materials (Figure S2). This suggests that the metal doping does not affect the morphology, although a slightly denser structure is observed when higher Ni loadings are used (Figure S2). In all cases, as shown via ADF-STEM and EDS chemical mapping (Figure 1B–Q), we observe a homogeneous distribution of Ni on the 3D-MoS\textsubscript{2}, no matter the percentage of the Ni-doping.

Figure 2 reports the XRD patterns and the Raman spectroscopy measurements on the Ni-doped 3D-MoS\textsubscript{2} samples. Figure 2A shows how the incorporation of Ni in the Mo\textsubscript{5} lattice affects the XRD patterns (in comparison with a pure 3D-MoS\textsubscript{2} sample). All the samples show four main peaks at 20 values of 13.8°, 33.1°, 39.3°, and 58.9° attributed to the (002), (100), (103), and (110) reflections of the hexagonal structure of 2H-MoS\textsubscript{2} [50].
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Figure 1. (A) SEM image of undoped 3D-MoS$_2$ undoped sample (scale bar: 2 μm). (B–Q) ADF-STEM/EDS analysis for the Ni-doped 3D-MoS$_2$ samples (scale bar: 300 nm). Energy-dispersive X-ray spectroscopy (EDS) mapping of Mo, S and Ni of 2% Ni, (C–E), 5% Ni (G–I), 10% Ni (K–M), and 15% Ni (O–Q), respectively.

A shift of the (002) peak to smaller 2θ values was observed for the undoped 3D-MoS$_2$ sample compared to bulk MoS$_2$, indicating an expansion along the c axis in 3D structured sample. 3D MoS$_2$ is a polycrystalline material with many structural defects that clearly interfere with the perfect stacking of the MoS$_2$ layers, thus, resulting in a larger distance between them. However, an opposite trend is observed for the 3D MoS$_2$ samples as the amount of Ni increases. The diffraction peaks slightly shift to higher 2θ values as the Ni content increases, suggesting a contraction of the MoS$_2$ lattice cell due to the incorporation of Ni into the MoS$_2$:structure as a consequence of the smaller atomic radius of Ni (1.49 Å) with respect to Mo (1.90 Å). The presence of Ni in the MoS$_2$:layers can cause the cross-linking between layers reducing the interlayer distance. In addition, the diffraction peaks become narrower when the Ni dose increases, which indicates that Ni induces the growth of larger MoS$_2$:crystallites above a certain amount (see below). No extra peaks associated with Ni sulfides/oxides are observed, further confirming the substitutional incorporation of Ni into the 3D-MoS$_2$:structure. The crystallite size was calculated from the (002) peak by using the Scherrer equation. The pure 3D-MoS$_2$:sample shows a crystallite size of 3.8 nm, that remains almost constant when a 2–5 at.% of Ni was added (~4.0 nm). However, when the Ni content is increased to 10 and 15 at.%, the crystallite size becomes 5 nm and 9.7 nm, respectively (see Figure 2B). Similar effects were recently observed in a microscopy study by Kondekar and co-workers, who undoubtedly demonstrated the strong influence in MoS$_2$:crystal growth from ATM precursor drop-casted on metallic Ni film [51]. Interestingly, in our samples, when the Ni amount reaches 10 at.% vs. Mo, a new peak at 38.3° appears, which, after careful comparison with literature, could not be associated with any NiS$_x$ or NiO$_x$. However, we could find a perfect match with the rarest MoS$_2$:polymorph named as 3R, which exhibits the same metal coordination of standard 2H-MoS$_2$:but with a shift of the layers. This is a clear indication that the introduction of Ni can induce a modification of both the crystal growth kinetics and the stacking sequence of the MoS$_2$:layers. The changes in the crystallite dimensions and in the stacking sequence can be also related to the formation of the [Ni(MoS$_4$)$_2$]$^{2-}$ complex in the precursor solution at higher Ni concentrations. These species may provide an alternative route for nucleation and growth with respect to the standard synthesis promoted by pure ATM [52,53].

Figure 2C shows the Raman spectra of the 3D-MoS$_2$:samples and a commercial bulk MoS$_2$:sample (Aldrich) as reference. All samples show two bands at approximately 380 and 405 cm$^{-1}$ that can be associated with the in-plane E$_{2g}^1$ and out-of-plane A$_{1g}$ vibrational modes, respectively, which are characteristic of 2H-MoS$_2$: [54]. Compared with the commercial powder, the 3D nanoarchitectures show a broader A$_{1g}$ band that can be associated with a smaller number of stacked layers along the c axis [55], confirming the limited growth and smaller size of the 3D-MoS$_2$:lamellae and the defective nature of these 3D materials. As the amount of Ni dopant increases, a very small shift of the A$_{1g}$ band toward lower values is observed (Figure 2D). The separation between the E$_{2g}^1$ and A$_{1g}$ modes is
usually adopted to calculate the number of stacked layers [55,56], indicating that high Ni loadings induce a higher stacking of the MoS\(_2\) layers, in agreement with the XRD results. However, the differences were not significant and all the materials with between 4 and 5 layers.

![Diagram](image)

Figure 2. XRD and Raman data of the Ni-doped 3D-MoS\(_2\) as a function of Ni loading. (A) XRD patterns, bulk MoS\(_2\) data are reported as a reference; (B) crystallite diameter and 2\(\theta\) (002) peak position; (C) Raman spectra; and (D) detail of A\(_{1g}\) peak for the 3D-MoS\(_2\) samples. Reference XRD data are the calculated pattern for 2H-MoS\(_2\) (blue line) and 3R-MoS\(_2\) (purple line).

XPS was used to investigate the incorporation of Ni in the 3D-MoS\(_2\) structure and the relative electronic effects, as it can reveal different chemical environments as well as variations of the electronic structure of the 3D-MoS\(_2\) scaffold [18]. First, the XPS data allowed obtaining the surface composition of the whole series of Ni-doped samples (see Supplementary Materials, Table S1): in all the cases, the Ni surface amount is proportional to the nominal Ni loading used in the synthesis. The Ni 2p\(_{3/2}\) region of the Ni-doped 3D-MoS\(_2\) is shown in Figure 3, whereas the corresponding Mo 3d and S 2p regions can be found in Figure S3. The Mo 3d and S 2p photoemission spectra of the commercial powder are also reported to assess the effect of the morphology on the electronic structure of the material. The Mo 3d peak of the bulk MoS\(_2\) was fitted using two doublets whose maxima are centered at a BE of 229.1 and 232.2 eV, respectively. The former is assigned to Mo(IV) in 2H-MoS\(_2\), and the latter to Mo(VI) in MoO\(_3\) surface oxide (due to the oxidation in air, 4 at.% of total Mo) (Figure S3). The Mo 3d peak was fitted with a single component at 161.8 eV in agreement with the values reported in the literature [57]. For pure 3D-MoS\(_2\), the deconvolution of Mo 3d peak revealed one main component at a BE of 228.9 eV (2H-MoS\(_2\)) and a smaller amount of MoO\(_x\) (232.1 eV) with respect to bulk MoS\(_2\) (1.3 at.%). This BE values of the Mo 3d\(_{5/2}\) guarantees that no amorphous [31] or metallic [58,59] MoS\(_2\) is present in the sample. The analysis of the S 2p region showed the presence of a single component at 161.7 eV, assigned to $S^{2-}$ species. Moreover, note that the absence of components related to a $S_2^{2-}$ dimer (expected at ca. 163.0 eV) is a clear indication that there is no residual precursor in the samples, so that the conversion from the ATM to MoS\(_2\) was complete [60,61]. The same analysis was performed on Ni-doped 3D-MoS\(_2\) samples and similar features were found, i.e., a main component attributed to 2H-MoS\(_2\), as well as a minor component related to MoO\(_x\) species (4–6 at.%, slightly
higher than pure 3D-MoS$_2$. A 0.1 eV shift toward lower BEs was observed in the MoS$_2$ component of the Mo 3d peak, compared with the pure sample. This shift can be attributed to the modification of the electronic environment of Mo due to the incorporation of Ni, which, according to the literature, is introduced in the MoS$_2$ lattice by substituting Mo atoms [34]. This is expected to have an effect on the electrochemical properties of MoS$_2$, as it indicates an electron-rich surface [18].

![Graphs showing Ni 2p$_{3/2}$ photoemission region for Ni-doped 3D-MoS$_2$ samples at different Ni loadings.](image1)

**Figure 3.** Multipeak analysis of Ni 2p$_{3/2}$ photoemission region for Ni-doped 3D-MoS$_2$ samples at different Ni loadings: (A) 2% Ni; (B) 5% Ni; (C) 10% Ni; (D) 15% Ni; (E) Evolution of Ni 2p$_{3/2}$ components as a function of the Ni content.

The Ni 2p$_{3/2}$ peak was separated into chemically shifted components to identify the Ni species. Three components at BEs of 853.5, 855.0, and 856.6 eV were included in the fit, which were attributed to NiS$_x$-like structure, Ni-Mo-S structure, and NiO$_x$ species, respectively, according to the literature [52,53,62–64]. Then, we analyzed the evolution of each component as a function of the Ni doping (Figure 3E, Table S2). We found a decrease of the lower BE component as the Ni amount increases, while the component at 855.0 eV followed the opposite trend. This suggests that, depending on the Ni amount, different Ni species are exposed, which may influence the electrocatalytic behavior.
Recently, electron microscopy measurements provided experimental evidence that the Ni atoms tend to segregate at the edges [65] and DFT calculations indicate that the formation energy of Ni at the S-edge is lower compared to all other possible structural configurations [65]. However, when inserted in the basal plane, the Ni tends to relax assuming the Ni–Mo–S structure, which is under-coordinated compared with Mo (4-fold S coordination vs 6-fold S for Mo), leaving unbound S atoms [35,66–71]; therefore, justifying the different chemical shift in XPS analysis. Finally, the NiO component is independent on the Ni content, being due to surface oxidation, and in all the samples is ~30 at.% of the total Ni amount.

3.2. Electrochemical Characterization

Figure 4 reports the electrochemical HER activities of the Ni-doped 3D-MoS 2 materials in alkaline and acid conditions. Commercial bulk MoS 2 (Aldrich) and 20 wt % Pt/C (Johnson Matthey) are also included for comparison. As performance descriptors, we report the Tafel slopes and the overpotentials at 10 mA cm 2 (\(\eta_{10mA/cm^2}\)) in Table 1. The Ni-doping of 3D-MoS 2 increases the activity in all cases, decreasing the overpotentials and increasing the current density. However, the differences observed among the Ni-doped 3D-MoS 2 samples leads to interesting considerations about the Ni species and their effect on the HER kinetics in acid and alkaline conditions. Note that the pure 3D-MoS 2 sample behaves similarly in acid and alkaline solutions, as expected from a polycrystalline material [17]. On the contrary, in presence of Ni doping, relevant differences are found by changing the pH.

![Figure 4](image)

**Figure 4.** Polarization curves and Tafel plots in 1.0M KOH (A,C) and in 0.5M H 2SO 4 (B,D), respectively, for the 3D-MoS 2 and Ni-doped 3D-MoS 2 materials.

In alkaline conditions, an increase of the activity with the amount of Ni is observed up to a 5 at.% doping (Figure 4A and Table 1), whereas higher Ni loadings result in a decrease of the activity. In the literature, it was reported that the doping of MoS 2 with Ni accelerates the HER kinetics in alkaline conditions by lowering the energy barrier for the water dissociation and OH desorption steps (see Scheme 1A) [19,20,72]. Late transition metals tend to form weaker bonds with OH with respect to Mo, favoring the by-products desorption. Moreover, as confirmed by XPS, the introduction
of Ni causes a slight electron enrichment of Mo, facilitating desorption of $H_{\text{ads}}$ species and therefore accelerating the Heyrovsky step [18,65,69–71].

### Table 1. Overpotentials at 10 mA cm$^{-2}$ and Tafel slopes for the undoped and Ni-doped 3D-MoS$_2$, commercial MoS$_2$ and 20 wt % Pt/C in 0.5M H$_2$SO$_4$ and 1.0M KOH.

<table>
<thead>
<tr>
<th>Material</th>
<th>Overpotential at 10 mA/cm$^2$ (V)</th>
<th>Tafel Slope (mV/dec)</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>0.5 M H$_2$SO$_4$</td>
<td>1.0 M KOH</td>
</tr>
<tr>
<td>Commercial</td>
<td>-</td>
<td>-</td>
</tr>
<tr>
<td>Undoped</td>
<td>0.35</td>
<td>0.35</td>
</tr>
<tr>
<td>2% Ni</td>
<td>0.34</td>
<td>0.27</td>
</tr>
<tr>
<td>5% Ni</td>
<td>0.25</td>
<td>0.22</td>
</tr>
<tr>
<td>10% Ni</td>
<td>0.30</td>
<td>0.29</td>
</tr>
<tr>
<td>15% Ni</td>
<td>0.35</td>
<td>0.33</td>
</tr>
<tr>
<td>Pt/C</td>
<td>0.02</td>
<td>0.17</td>
</tr>
</tbody>
</table>

From the different Ni species distribution determined from XPS, an interesting correlation between the structural parameters and the HER activity comes up. The activity increases as a function of the amount of Ni atoms in NiS$_x$ structures up to a 5 at.% doping, then starts to decrease when the Ni–Mo–S structure sets in (see Figure 3E and Table S2). The total amount of NiS$_x$ sites always increases with the Ni content, however the HER activity decreases for loadings higher than 10 at.%.

Indeed, as demonstrated above, higher Ni loading induces the growth of larger crystallites and a denser morphology of these materials. Clearly, these modifications result in a smaller surface area exposed to the electrolyte and, especially, in a lower amount of exposed active sites due to the bigger size of the crystallites. This is further proved by Electrochemical Impedance Spectroscopy (EIS) experiments, where higher charge transfer resistance and smaller exchange currents were measured (see Figure S4 and Table S3). This result suggests that the Ni-Mo-S structure is not able to promote the HER activity in alkaline medium as effectively as the NiS$_x$ sites do. This is also confirmed by the analysis of the HER kinetics through the Tafel slope values (Table 1). They follow the same trend as the HER activity, that is, the Tafel slope decreases with the amount of Ni up to a 5 at.% Ni-doping and increases for higher Ni loadings. The lowest value, 65 mV dec$^{-1}$, is obtained for the 5 at.% Ni–MoS$_2$ sample, and is one of the lowest reported in the literature for Ni doped MoS$_2$ [65].

In acidic conditions, HER activities interestingly show some differences with respect to those observed in alkaline media, suggesting variations in the involved active sites. The introduction of 2 at.% Ni does not induce any enhancement of the HER activity, in terms of both onset potential and current density with respect to the pristine 3D-MoS$_2$, contrary to what happens in alkaline media. This result suggests that the NiS$_x$ sites, i.e., the main Ni species in this sample, do not have any role in the HER mechanism. However, a further increase of Ni-doping up to 5 at.% significantly improves the HER activity by decreasing the $\eta_{10mA/cm^2}$ by 0.1 V. Compared to the 2% Ni-MoS$_2$ sample, the relative amount of NiS$_x$ species decreases in the 5% Ni sample, whereas the Ni-Mo-S component becomes larger. Therefore, considering that we observed that NiS$_x$ sites are inactive in acidic environment (see Figure 4B) [18], we could attribute the enhancement of HER activity to the Ni-Mo-S sites. When the amount of Ni-Mo-S species further increases (10% and 15% Ni samples), the HER is enhanced compared with the pristine and 2% Ni-MoS$_2$ sample, confirming the key role of these species. However, these materials show a lower activity than the 5% Ni-MoS$_2$ sample, due to the increase of charge transfer resistance (see Figure S5 and Table S3) caused by the enlargement of the particle size, as mentioned above.
To elucidate the role of the different Ni species, a modelistic approach to the structural changes caused by the addition of Ni must be considered. The NiS$_x$-like species (scheme 1A) allows to reduce the adsorption energy in alkaline conditions, so lowering the energy barrier for the water dissociation and OH$^-$ desorption steps because the M–OH bond formed is weaker than with Mo [19,20]. On the other hand, the Ni–Mo–S structure in MoS$_2$ adopt a relaxed structure, leaving two unbound sulfur atoms as shown in Scheme 1B. In agreement with the literature [18,35,73], the presence of these unsaturated S atoms can favor the proton adsorption step (Volmer step), which is the rate determining step for pure MoS$_2$, as demonstrated by Tafel analysis. The lowering of the Tafel slope with the addition of Ni confirms the acceleration of the proton adsorption. Moreover, as in the case of HER in alkaline medium, XPS data proved the surface electron enrichment induced by Ni; therefore, the adsorption strength of H atom decreases. This would facilitate the subsequent H recombination and release processes, thus accelerating the overall reaction kinetics [18,74–76]. Interestingly, the decay of the kinetics in the samples with highest loading and crystallites size (10 and 15% Ni) is faster in alkaline conditions. This indicates that the abundance of Ni-Mo-S sites allows a preferential pathway for protons adsorption cleaving H$^+$–OH$_2$ molecules, but not for the adsorption and the dissociation of neutral water molecules at higher pH.

Finally, the long-term stability of the samples under HER working condition was investigated by chronopotentiometric measurements. Figures S6 and S7 show the V-t curves obtained in alkaline and acid environment, respectively. As observed, the performances are in good agreement with the results showed in Figure 4. The materials presented a high stability in alkaline conditions. The stability in acid conditions was good but a bit lower than in alkaline conditions.

4. Conclusions

In this work, we studied the effect of the introduction of different amounts of Ni on the structure and on the electrocatalytic performances of 3D-structured MoS$_2$ architectures. We observed that large quantities of dopant can strongly influence the catalyst structure, by modifying the nucleation and growth processes, which has an important effect on the HER performances. Thanks to an accurate XPS analysis of the Ni species formed, we identified the ones that promote the HER mechanism in alkaline and acid media: the NiS$_x$ species are key to promote HER in alkaline medium, whereas the Ni–Mo–S ones enhanced the HER in acid medium. Therefore, the insertion of Ni into the MoS$_2$ scaffold may induce not only a different crystallization path, but also different kind of Ni-based sites with different activities. Both factors have a strong influence on the electrochemical performance of the final catalyst.

**Supplementary Materials:** The following are available online at www.mdpi.com/xxx/s1, Figure S1: Polarization curves (left) and Tafel plot (right) for undoped 3D-MoS$_2$ materials prepared with different starting solutions,
Figure S2: SEM images of Bulk MoS2, undoped 3D-MoS2 and Ni-doped 3D-MoS2 samples (scale bar: 2 µm), Figure S3: Mo 3d and S 2p XPS regions for Bulk MoS2, undoped and Ni-doped 3D-MoS2 samples. Dotted lines in graphs refer to BE values found for undoped 3D-MoS2, Figure S4: Nyquist plot for doped and undoped 3D-MoS2 at η = 0.28 V in 1.0 M KOH, Figure S5: Nyquist plot for doped and undoped 3D-MoS2 at η = 0.28 V in 0.5 M H2SO4, Figure S6: Chronopotentiometric stability test at 10 mA cm−2 in 1.0 M KOH, Figure S7: Chronopotentiometric stability test at 10 mA cm−2 in 0.5 M H2SO4, Table S1: Surface composition of Bulk MoS2, undoped and Ni-doped 3D-MoS2 materials, Table S2: Composition of Ni 2p3/2 photoemission line, Table S3: Charge transfer resistance (Rct) and exchange currents (i0) calculated in 0.5 M H2O2 and 1.0 M KOH.


Funding: This work was partially supported by the Italian MIUR through the two PRIN projects: SMARTNESS (2015K7FZLH) and MULTI-e (20179337R7). The MAECI (Ministero degli Affari Esteri e della Cooperazione Internazionale, Direzione Generale per la Promozione del Sistema Paese) is gratefully acknowledged for the bilateral Italy–China GINSENG (PGR00953) project.

Acknowledgments: Authors would like to thank Prof. Nicolas Alonso-Vante for critical discussions.

Conflicts of Interest: The authors declare no conflicts of interest.

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Surfaces 2019, 2, 39


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